

Mems Oscillator, High Performance Differential Oscillator, LVPECL and LVDS 220.00 MHz to 625.00MHz IM841 Series

Features:

- MEMS Technology
- Direct pin to pin drop-in replacement for industry-standard packages
- 0.6 pSec RMS phase jitter (random) over 12 kHz to 20 MHz bandwidth
- LVPECL and LVDS output signaling types
- Industry-standard package 3.2 x 2.5, and 5.0 x 3.2 mm x mm
- Pb-free, RoHS and REACH compliant

Typical Applications:

- Fibre Channel
- Server and Storage
- GPON, EPON
- 100M / 1G /10G Ethernet

Electronic Specifications:

Frequency Range	220.000 MHz to 625.000 MHz	
Frequency Stability	See Part Number Guide	Inclusive of all changes in Operating Temp. Range, Load, and Voltage
First Year Aging	±2.0 ppm max	+25°C ±2.0°C
10 Years Aging	±5.0 ppm max	+25°C ±2.0°C
Operating Temperature	See Part Number Guide	
Supply Voltage (Vdd) ±10%	See Part Number Guide	
Input Voltage High	70% of Vdd min	Pin 1, OE or \overline{ST}
Input Voltage Low	30% of Vdd max	Pin 1, OE or \overline{ST}
Input Pull-up Impedance	100 kΩ typ., 250 kΩ max 2.0 MΩ min	Pin 1, OE logic high or logic low, or \overline{ST} logic high Pin 1, \overline{ST} logic low
Start-up Time	6.0 mSec typ., 10.0 mSec max	Measured from the time Vdd reaches its rated minimum values
Resume Time	6.0 mSec typ., 10.0 mSec max	Measured from the time \overline{ST} pin crosses 50% threshold.
Symmetry	45%/55%	

LVPECL, DC and AC Characteristics

Current Consumption	61 mA typ., 69 mA max	Excluding Load Termination Current, Vdd = +3.3 V or +2.5 V
OE Disable Supply Current	35 mA max	OE = Low
Output Disable Leakage Current	1 μA max	OE = Low
Standby Current	100 μA max	\overline{ST} = Low, for all Vdds
Maximum Output Current	30 mA max	Max average current drawn from OUT+ or OUT-
Logic "1"	Vdd -1.1 min / Vdd - 0.7 max	See figure 1(a)
Logic "0"	Vdd -1.9 min / Vdd - 1.5 max	See figure 1(a)
Output Differential Voltage Swing	1.2 V min. 1.6V typ., 2.0 V max	See figure 1(b)
Rise/Fall Time	300 pSec typ., 500 pSec max	20% to 80%, see figure 1(a)
OE Enable/Disable Time	115 nSec max	F = 220.00 MHz – For other frequencies, T _{oe} = 100nSec + 3 period
RMS Period Jitter	1.2 pSec typ., 1.7 pSec max 1.2 pSec typ., 1.7 pSec max 1.2 pSec typ., 1.7 pSec max	F = 266.00 MHz, Vdd = +3.3 V or +2.5 V F = 312.50 MHz, Vdd = +3.3 V or +2.5 V F = 622.08 MHz, Vdd = +3.3 V or +2.5 V
RMS Phase Jitter (random)	0.60 pSec typ, 0.85 pSec max.	F = 312.50 MHz, Integration Bandwidth = 12 kHz to 20 MHz all Vdds

LVDS, DC and AC Characteristics

Current Consumption	47 mA typ., 55 mA max	Excluding Load Termination Current, Vdd = +3.3 V or +2.5 V
OE Disable Supply Current	35 mA max	OE = Low
Differential Output Voltage	250 mV min, 350 mA typ. 450 mV max	See Figure 2
Output Disable Leakage Current	1 μA max	OE = Low
Standby Current	100 μA max	\overline{ST} = Low, for all Vdds
VOD Magnitude Change	50 mV max	See Figure 2
Offset Voltage	1.125 mV min, 1.200 mV typ., 1.375 mV max	See Figure 2
VOS Magnitude Change	50 mV max	See Figure 2
Rise/Fall Time	495 pSec typ., 600 pSec max	20% to 80%, See Figure 2
OE Enable Time/Disable Time	115 nSec max	F = 220.00 MHz, For other Frequencies, T _{oe} =100nSec + 3 period
RMS Period Jitter	1.4 pSec typ., 1.7 pSec max 1.4 pSec typ., 1.7 pSec max 1.2 pSec typ., 1.7 pSec max	F = 266.00 MHz, Vdd = +3.3 V or +2.5 V F = 312.50 MHz, Vdd = +3.3 V or +2.5 V F = 622.08 MHz, Vdd = +3.3 V or +2.5 V
RMS Phase Jitter (random)	0.60 pSec typ., 0.85 pSec max	F = 312.50 MHz, Integration Bandwidth = 12 kHz to 20 MHz all Vdds

Notes:

- All min and max limits are specified over temperature and rated operating voltage with 15pF output unless otherwise stated.
- Typical values are at +25°C and nominal supply voltage.

Ordering Information:

Part Number Guide						
Packages	Input Voltage	Operating Temperature	Stability (ppm)	Output	Select Function	Frequency
IM841B – 5.0 x 3.2 IM841C – 3.2 x 2.5	6 = +2.5 V 3 = +3.3 V	1 = 0°C to +70°C 2 = -40°C to +85°C 3 = -20°C to +70°C	E = ±10 F = ±20 A = ±25 Z = ±30 B = ±50	8 = LVDS 9 = LVPECL	H = Tri-state S = Standby	- Frequency

Sample Part Number: IM841C-62F9S-100.0000MHz

This 100.0000 MHz oscillator in a 3.2 x 2.5 package with stability ±20 ppm from -40°C to +85°C using a supply voltage of +2.5 V. With an output waveform of LVPECL and Pin 1 functioning as Standby

Sample Part Number: IM841B-33Z8H-150.0000MHz

This 150.0000 MHz oscillator in a 5.0 x 3.2 package with stability ±30 ppm from -20°C to +70°C using a supply voltage of +3.3 V. With an output waveform of LVDS and Pin 1 functioning as Tri-state.

Notes:

- Not all options are available at all frequencies and temperatures ranges.
- Please consult with sales department for any other parameters or options.
- Oscillator specification subject to change without notice.

Absolute Maximum Limits	
Storage Temperature	-65°C to +150°C
Supply Voltage (Vdd)	-0.5 VDC to 4.0 VDC
Electrostatic Discharge	2000 V max
Solder Temperature (follow standard Pb free soldering guidelines)	260°C max
Junction Temperature	150°C max

Waveform Diagrams:

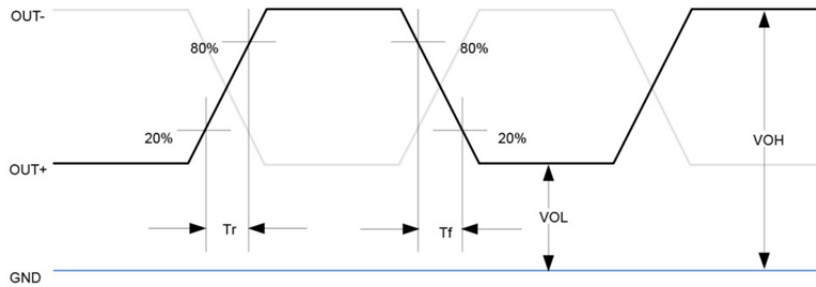


Figure 1(a): LVPECL Voltage Levels per Differential Pin (OUT+/OUT-)

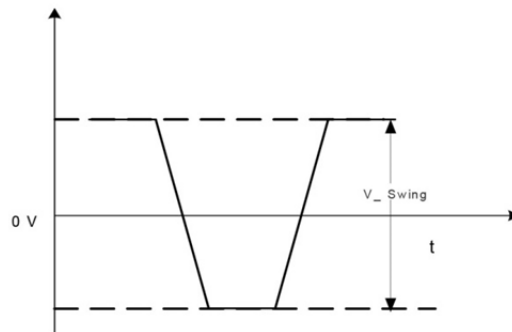


Figure 1(b): LVPECL Voltage Levels Across Differential Pair

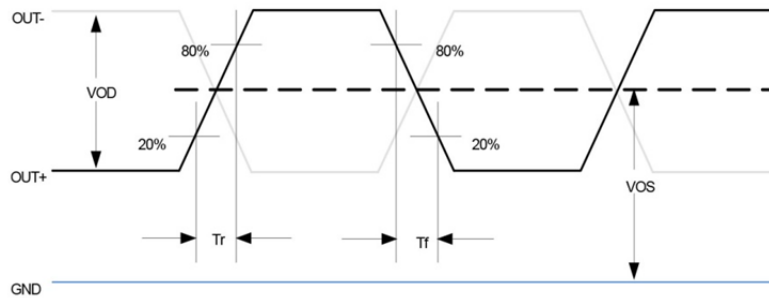


Figure 2: LVDS Voltage Levels per Differential Pin (OUT+/OUT-)

Termination Diagrams – LVPECL:

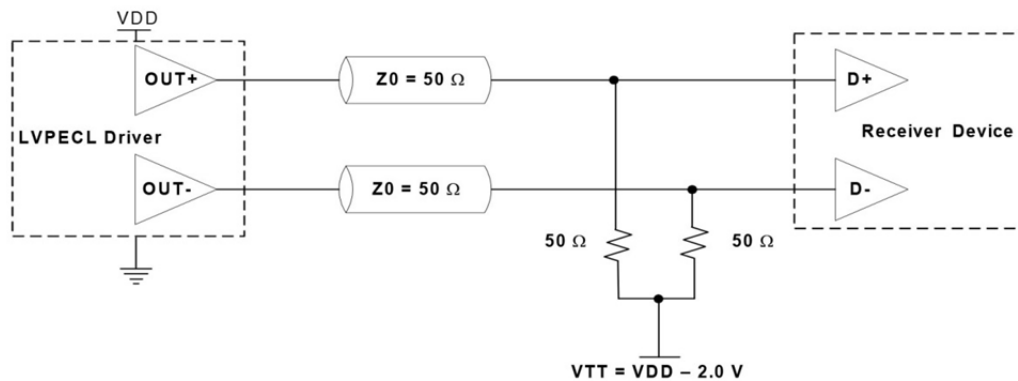


Figure 3: LVPECL Typical Termination

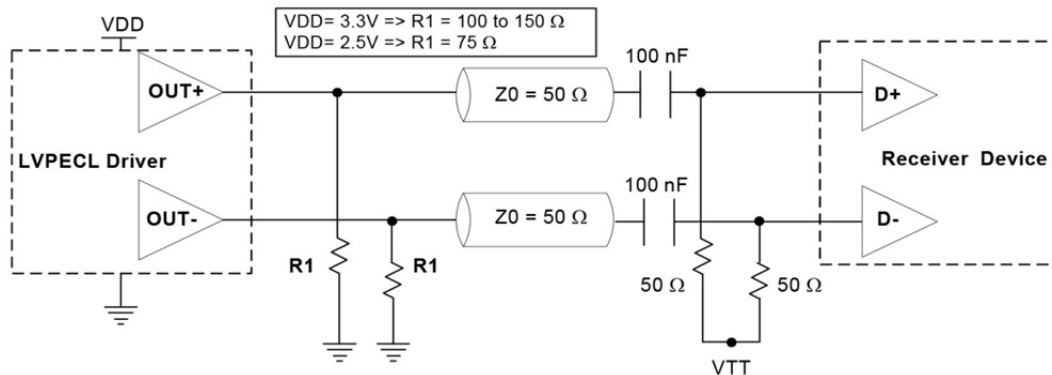


Figure 4: LVPECL AC Coupled Termination

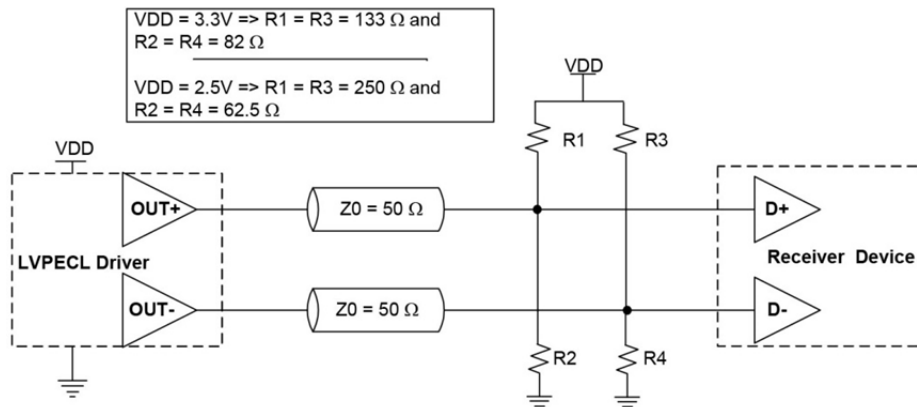


Figure 5: LVPECL with Thevenin Typical Termination

Termination Diagram – LVDS:

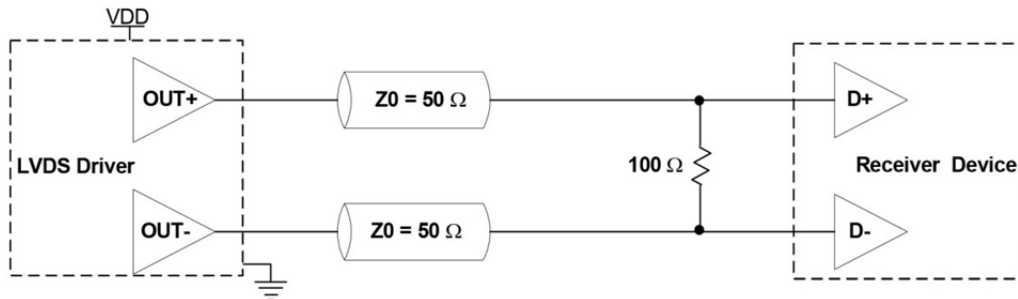
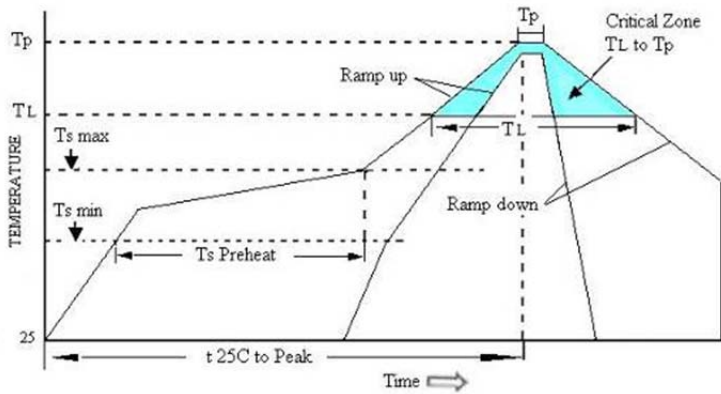


Figure 6: LVDS Single Termination (Load Terminated)

Environmental Specifications:

Environmental Compliance	
Parameter	Condition/Test Method
Mechanical Shock	MIL-STD-883F, Method 2002
Mechanical Vibration	MIL-STD-883F, Method 2007
Temperature Cycle	JESD22, Method A104
Solderability	MIL-STD-883F, Method 2003
Moisture Sensitivity Level	MSL Level 1 at +260°C

Pb Free Solder Reflow Profile

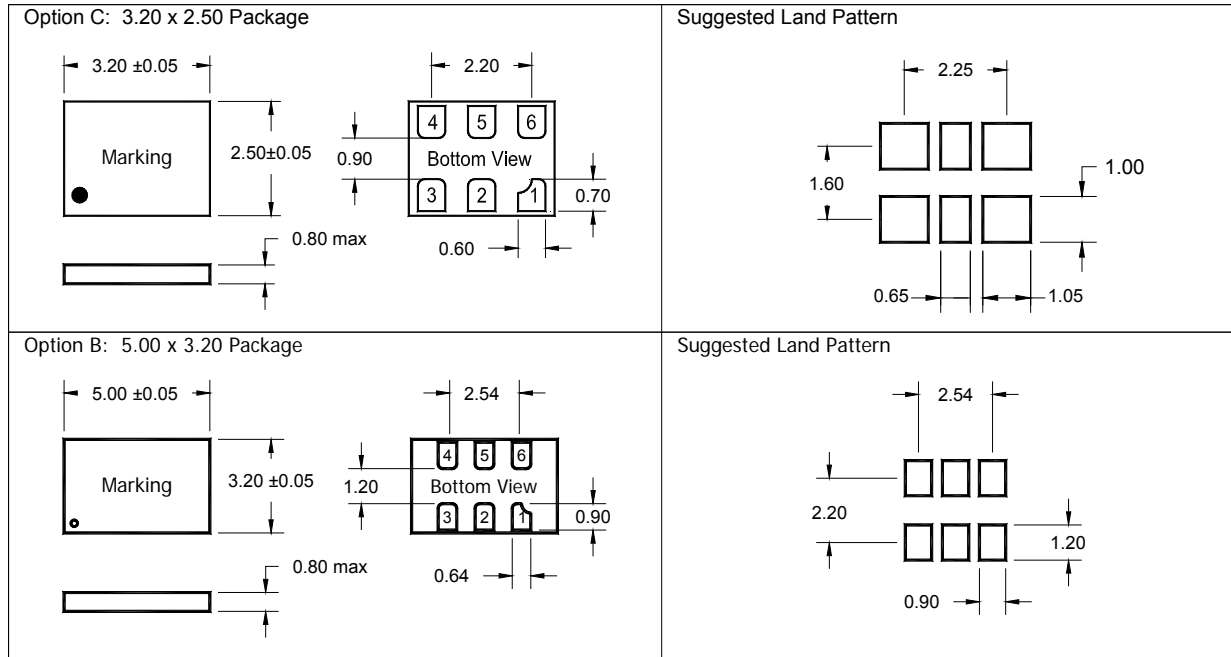


Ts max to T _L (Ramp-up Rate)	3°C / second max
Preheat	
Temperature min (Ts min)	150°C
Temperature typ (Ts typ)	175°C
Temperature max (Ts max)	200°C
Time (Ts)	60 to 180 seconds
Ramp-up Rate (T _L to T _p)	3°C / second max
Time Maintained Above Temperature (T _L)	217°C
Time (T _L)	60 to 150 seconds
Peak Temperature (T _p)	260°C max for seconds
Time within 5°C to Peak Temperature (T _p)	20 to 40 seconds
Ramp-down Rate	6°C / second max
Time 25°C to Peak Temperature	8 minute max
Moisture Sensitivity Level (MSL)	Level 1

Units are backward compatible with +240°C reflow processes

Mechanical Details:

Package Dimensions and Suggested Land Pattern



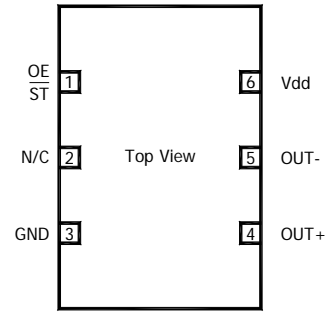
Marking

Line 1 = XXXXX (Lot code)
Dot to denote Pin 1 location

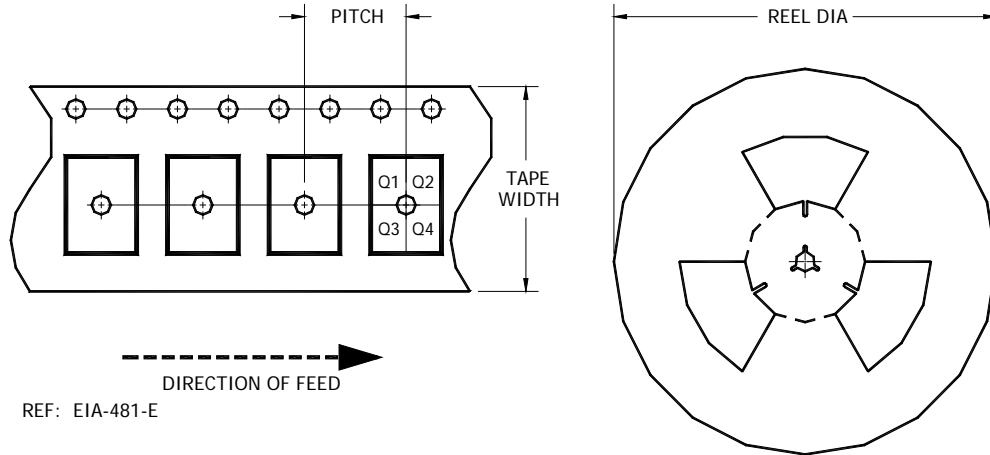
Package Information

Leadframe: C194
Plating: NiPdAu

Pin Functionally:

Pin	Symbol	Functionality		Pin Assignments
1	OE	Tri-state	High or Open = specified frequency output Low = Output is high impedance, only output is disabled.	
	\overline{ST}	Standby	High or Open = specified frequency output. Low = Output is low (weak pull down). Device goes to sleep mode. Supply current reduces to standby current.	
2	NC	NA	No Connection: Leave it floating or connected to GND for better head dissipation	
3	GND	Power	Vdd – Power Supply Ground	
4	Out+	Output	Oscillator output	
5	Out-	Output	Complementary Oscillator output	
6	Vcc	Power	Power supply voltage	
<p>Notes:</p> <ol style="list-style-type: none"> In OE or \overline{ST} mode, a pull-up resistor of 10.0 kΩ or less is recommended if Pin 1 is not externally driven. If Pin 1 needs to be left floating, use the NC option. A capacitor of value 0.1 μF or higher between Pin 4 (Vcc) and Pin 1 (GND) is required. 				

Tape and Reel Dimensions



Part Number	Size	Pitch	Tape Width	Pin Orient.	Reel Dia.	Count
IM841B	5.0 x 3.2	4.0 ± 0.1	8.3 max	Q1	180 Dia	3000
IM841C	3.2 x 2.5	4.0 ± 0.1	8.3 max	Q1	180 Dia	3000

Notes:

- All dimensions are in mm.
- Do not scale drawings.

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